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# H5N5005PL

# Silicon N Channel MOS FET High Speed Power Switching

REJ03G0419-0400 Rev.4.00 May 13, 2009

### **Features**

• Low on-resistance:  $R_{DS(on)} = 0.070 \Omega$  typ.

• Low leakage current:  $I_{DSS} = 10 \propto A \text{ max (at } V_{DS} = 500 \text{ V})$ 

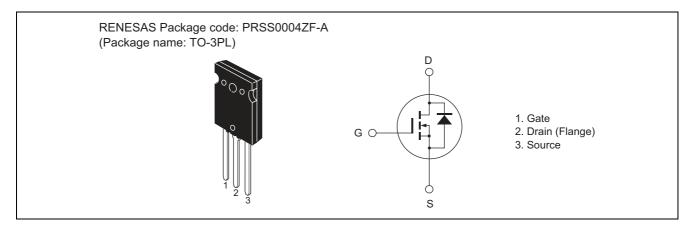
• High speed switching:  $t_f$  = 300 ns typ (at  $V_{GS}$  = 10 V,  $I_D$  = 30 A,  $R_L$  = 8.33  $\Omega$ )

• Low gate charge: Qg = 300 nC typ (at  $V_{DD} = 400 \text{ V}$ ,  $V_{GS} = 10 \text{ V}$ ,  $I_D = 60 \text{ A}$ )

• Avalanche ratings

• Built-in fast recovery diode:  $t_{rr} = 220$  ns typ

### **Outline**



## **Absolute Maximum Ratings**

 $(Ta = 25^{\circ}C)$ 

Item	Symbol	Ratings	Unit
Drain to Source voltage	$V_{DSS}$	500	V
Gate to Source voltage	V <sub>GSS</sub>	±30	V
Drain current	I <sub>D</sub>	60	Α
Drain peak current	I <sub>D (pulse)</sub> Note1	240	Α
Body-Drain diode reverse Drain current	I <sub>DR</sub>	60	Α
Body-Drain diode reverse Drain peak current	I <sub>DR (pulse)</sub> Note1	240	Α
Avalanche current	I <sub>AP</sub> Note3	30	Α
Channel dissipation	Pch Note2	270	W
Channel to case thermal impedance	θch-c	0.463	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW ≤ 10 ∞s, duty cycle ≤ 1%

2. Value at Tc = 25°C

3. STch =  $25^{\circ}$ C, Tch  $\leq 150^{\circ}$ C

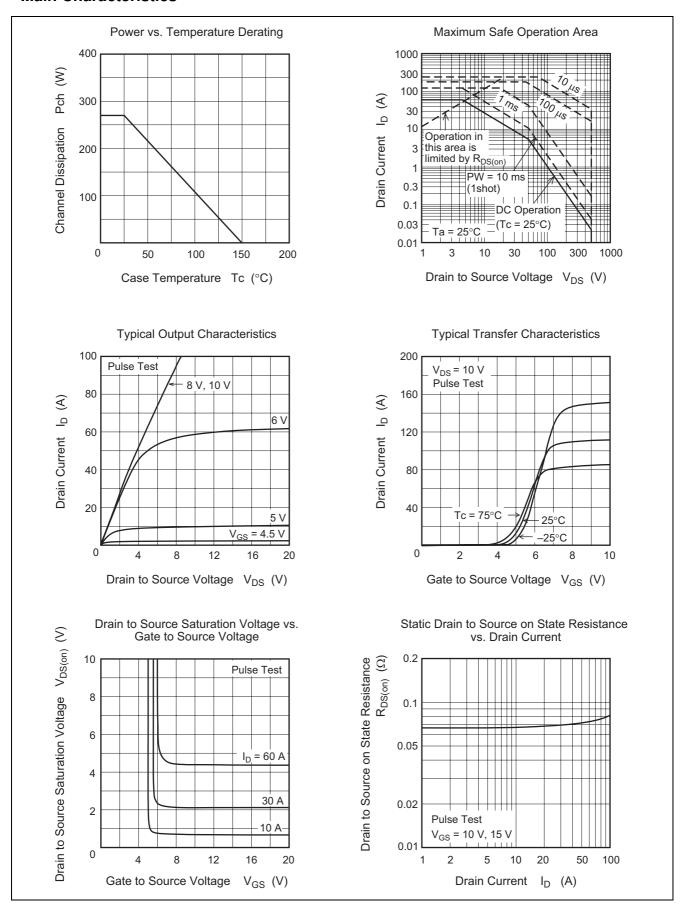
# **Electrical Characteristics**

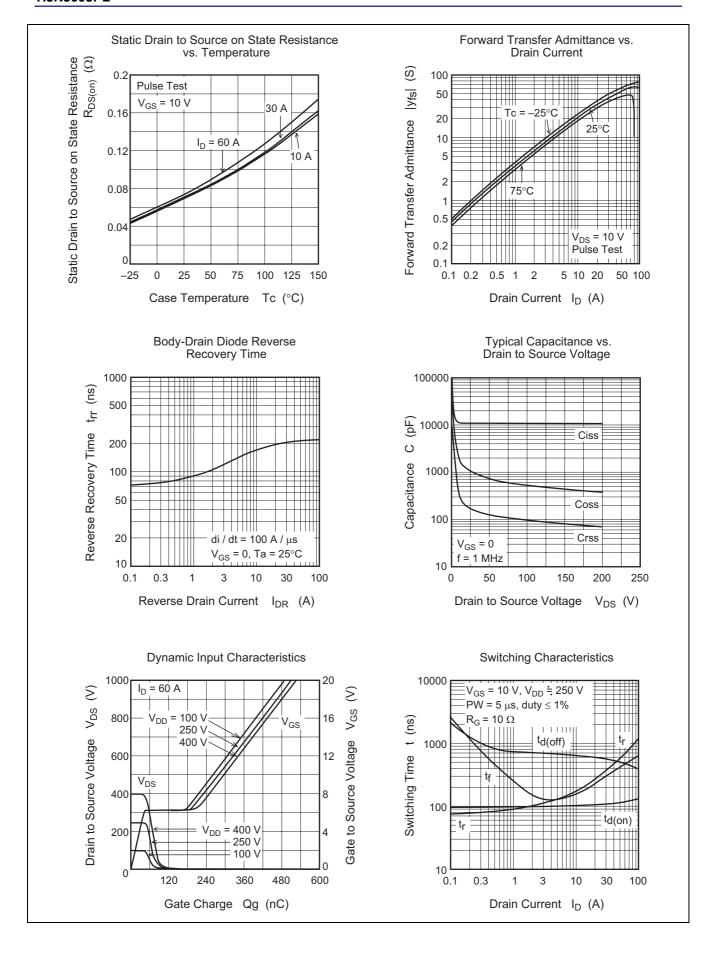
 $(Ta = 25^{\circ}C)$ 

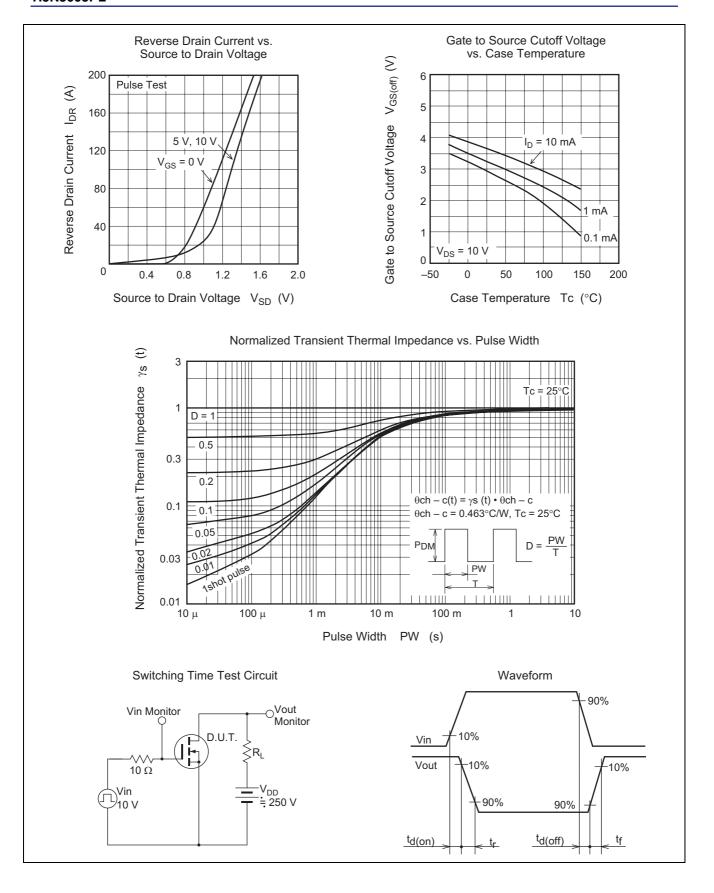
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to Source breakdown voltage	$V_{(BR)DSS}$	500		_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Zero Gate voltage Drain current	I <sub>DSS</sub>	_	_	10	∞A	V <sub>DS</sub> = 500 V, V <sub>GS</sub> = 0
Gate to Source leak current	I <sub>GSS</sub>	_	_	±0.1	∝A	$V_{GS} = \pm 30 \text{ V}, V_{DS} = 0$
Gate to Source cutoff voltage	$V_{GS(off)}$	2.0	_	4.0	V	$V_{DS} = 10 \text{ V}, I_{D} = 1 \text{ mA}$
Forward transfer admittance	y <sub>fs</sub>	25	42	_	S	$I_D = 30 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Static Drain to Source on state resistance	R <sub>DS(on)</sub>	_	0.070	0.085	Ω	$I_D = 30 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	10550	_	pF	V <sub>DS</sub> = 25 V
Output capacitance	Coss	_	1060	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	180	_	pF	f = 1 MHz
Turn-on delay time	t <sub>d(on)</sub>	_	115	_	ns	I <sub>D</sub> = 30 A
Rise time	t <sub>r</sub>	_	380	_	ns	V <sub>GS</sub> = 10 V
Turn-off delay time	$t_{d(off)}$	_	560	_	ns	$R_L$ = 8.33 $Ω$ Rg = 10 $Ω$
Fall time	t <sub>f</sub>	_	300	_	ns	
Total Gate charge	Qg	_	300	_	nC	V <sub>DD</sub> = 400 V
Gate to Source charge	Qgs	_	40	_	nC	V <sub>GS</sub> = 10 V
Gate to Drain charge	Qgd	_	155	_	nC	I <sub>D</sub> = 60 A
Body-Drain diode forward voltage	$V_{DF}$	_	1.0	1.5	V	I <sub>F</sub> = 60 A, V <sub>GS</sub> = 0 <sup>Note4</sup>
Body-Drain diode reverse recovery time	t <sub>rr</sub>	_	220	_	ns	$I_F = 60 \text{ A}, V_{GS} = 0$ $di_F/dt = 100\text{A}/\infty\text{S}$
Body-Drain diode reverse recovery charge	Q <sub>rr</sub>	_	2.0	_	∝C	

Note: 4. Pulse test

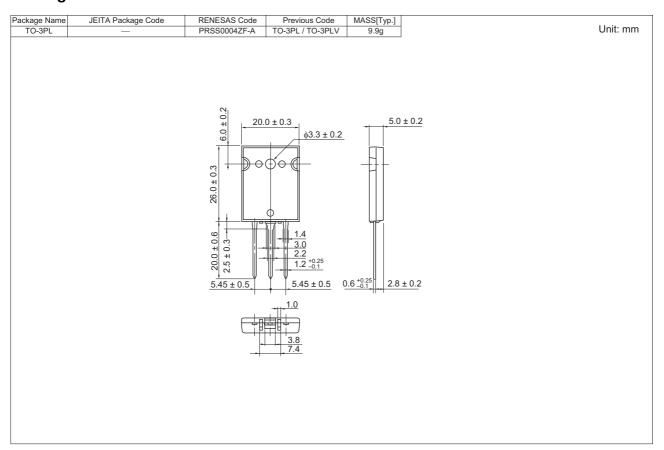
### **Main Characteristics**







# **Package Dimensions**



# **Ordering Information**

Part Name	Quantity	Shipping Container
H5N5005PL-E	250 pcs	Box (Tube)

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